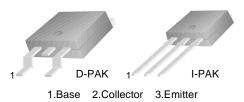
# FAIRCHILD

SEMICONDUCTOR®

# MJD41C

## General Purpose Amplifier Low Speed Switching Applications D-PAK for Surface Mount Applications

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular TIP41 and TIP41C



## **NPN Epitaxial Silicon Transistor**

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ι <sub>C</sub>	Collector Current (DC)	6	А
I <sub>CP</sub>	Collector Current (Pulse)	10	А
I <sub>B</sub>	Base Current	2	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
	Collector Dissipation (T <sub>a</sub> =25°C)	1.75	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

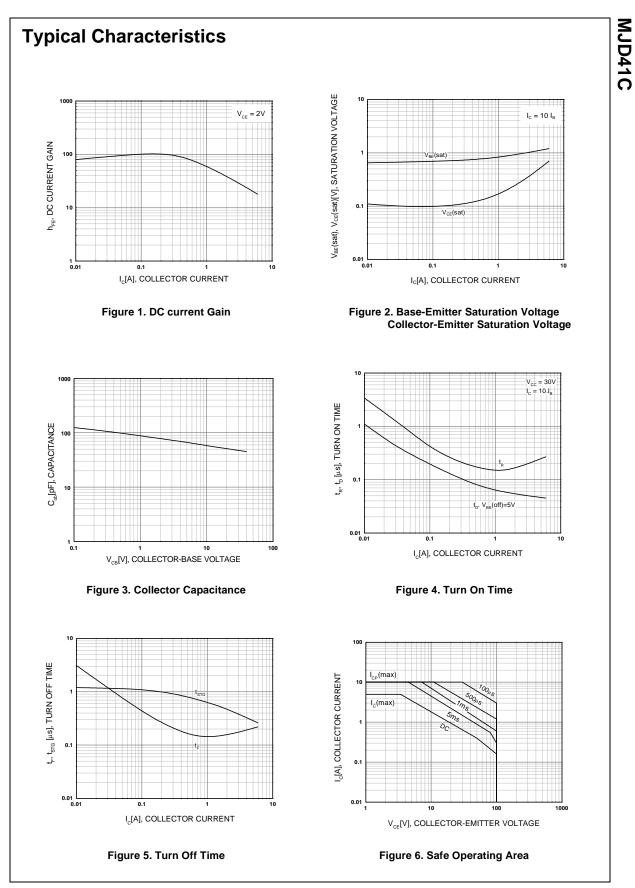
## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage	$I_{\rm C} = 30 {\rm mA}, I_{\rm B} = 0$	100		V
I <sub>CEO</sub>	Collector Cut-off Current	$V_{CE} = 60V, I_B = 0$		50	μΑ
I <sub>CES</sub>	Collector Cut-off Current	V <sub>CE</sub> = 100V, V <sub>BE</sub> = 0		10	uA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$		0.5	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = 4V, I_{C} = 0.3A$	30		
		$V_{CE} = 4V, I_{C} = 3A$	15	75	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = 6A, I <sub>B</sub> = 600mA		1.5	V
V <sub>BE</sub> (on)	* Base-Emitter ON Voltage	$V_{CE} = 6A, I_C = 4A$		2	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 500mA$	3		MHz

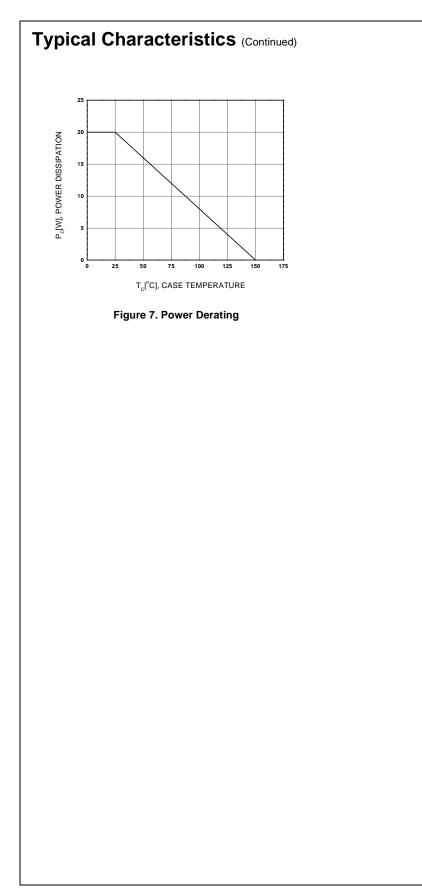
\* Pulse Test: PW≤300µs, Duty Cycle≤2%

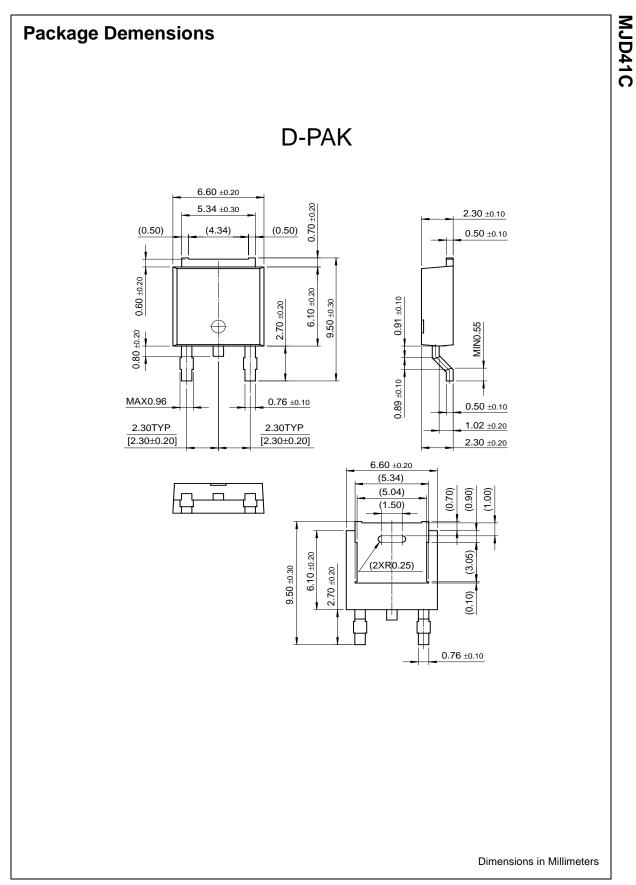
MJD41C



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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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